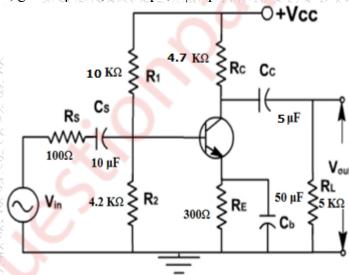
1T01124 - S.E.(ELECTRONICS)(Sem IV)(Choice Based) / 40902 - ELECTRONICS DEVICES & CIRCUITS II

Three Hours 80 Marks

- N.B. 1) **Question-1** is compulsory.
  - 2) Solve any **Three** questions from the remaining.
  - 3) Assume suitable data wherever necessary.
  - 4) All questions carry equal marks.
- Q.1 Solve any **four** of the following:
  - a) Explain cross over distortion in Class B power amplfier.
  - b) Explain Darlington pair amplifier.
  - c) Explain Gunn diode.
  - d) Explain high frequency equivalent circuit of MOSFET.
  - e) Draw MOSFET differential amplifier with active load.
- Q.2 a) Explain working of TRIAC with construction and V-I characteristics. Also give its applications.
  - b) Explain voltage series and current shunt feedback amplifiers.
- Q.3 a) Calculate lower cut off frequency of the following circuit.

 $\beta$ =100,  $r_{\pi}$ =1.5KΩ,  $g_{m2}$ =50μA/V,  $C_{\pi}$ =15pF,  $C_{\mu}$ =1pF



- b) Explain UJT as a relaxation oscillator with neat circuit diagram.
- Q.4 a) Explain Class A power amplifier with circuit diagram and derive equation for efficiency.
  - b) Explain small signal analysis for MOSFET active load circuit.

10 10

10

20

10

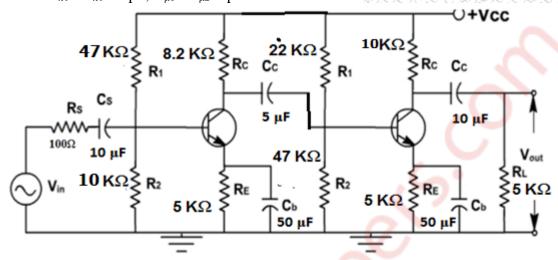
**10** 

10

66430

Q.5 a) Calculate bandwidth for two stages RC coupled CE amplifier shown in the circuit below: 10

$$\begin{array}{l} \beta_1 \!\!=\! \beta_2 \!\!=\! 100, \, r_{\pi 1} \!\!=\! r_{\pi 2} \!\!=\! 1.5 K \Omega, \, g_{m 1} \!\!=\! g_{m 2} \!\!=\! 50 mA/V \\ C_{\pi 1} \!\!=\! C_{\pi 1} \!\!=\! 10 pF, \, C_{\mu 1} \!\!=\! C_{\mu 2} \!\!=\! 5 pF \end{array}$$



b) Explain Hartley oscillator. Design the same for 5MHz.

**10** 

Q.6 Write short notes on any **three** of the following:

20

- a) SCR
- b) Wein bridge oscillator.
- c) Cascode BJT amplifier
- d) Class B push pull power amplifier

\*\*\*\*\*\*

66430

Page 2 of 2